# 2SA1499

### Silicon PNP epitaxial planar type

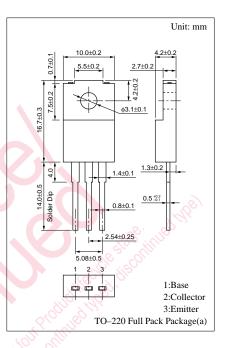
#### For high-speed switching

#### Features

- $\bullet \ \ High \ foward \ current \ transfer \ ratio \ h_{FE}$
- High-speed switching
- High collector to base voltage V<sub>CBO</sub>
- Full-pack package which can be installed to the heat sink with one screw.

Absolute Maximum Ratings $(1_c=25 \text{ C})$							
Parameter		Symbol	Ratings	Unit			
Collector to base voltage		V <sub>CBO</sub>	-400	V			
Collector to emitter voltage		V <sub>CEO</sub>	-400	V			
Emitter to base voltage		V <sub>EBO</sub>	-7	V			
Peak collector current		I <sub>CP</sub>	-1.2	A			
Collector current		I <sub>C</sub>	- 0.6	A			
Collector power	T <sub>C</sub> =25°C	D	25	11/			
dissipation	Ta=25°C	P <sub>C</sub>	2	W			
Junction temperature		Tj	150	°C			
Storage temperature		T <sub>stg</sub>	-55 to +150	°C			

#### Absolute Maximum Ratings (T<sub>C</sub>=25°C)

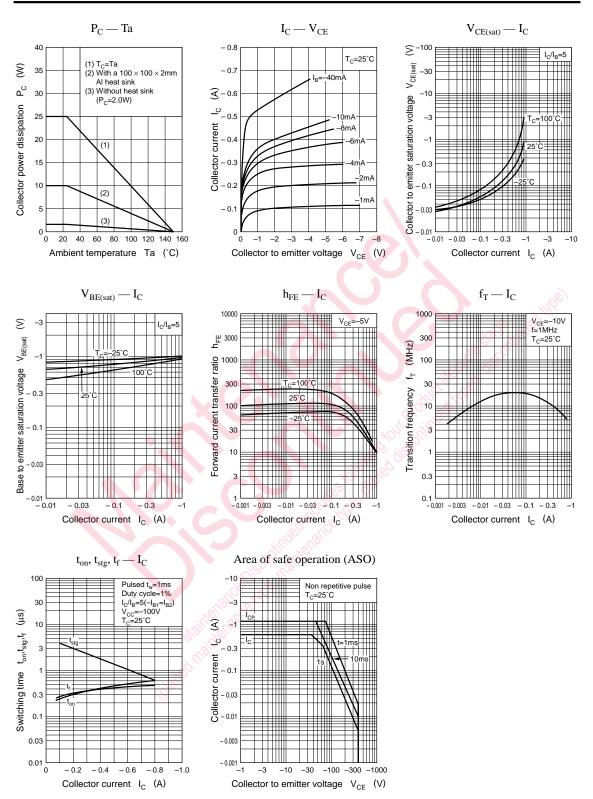


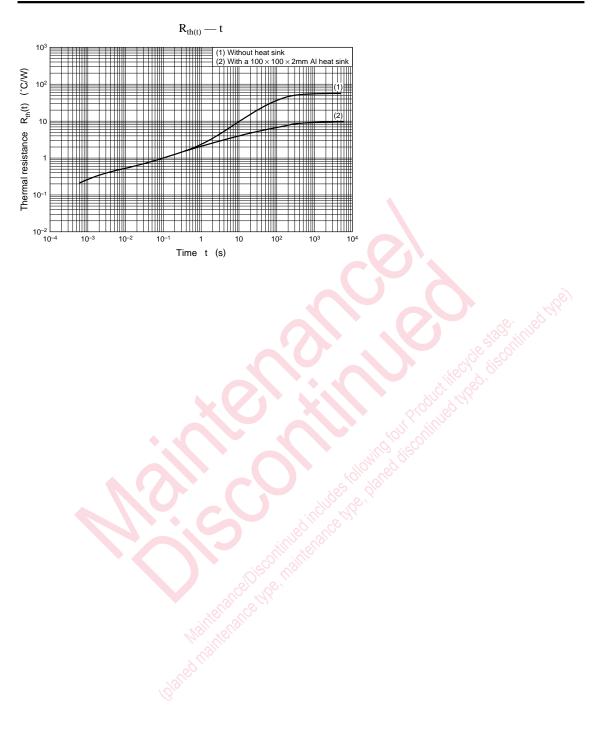
#### Electrical Characteristics (T<sub>c</sub>=25°C)

Parameter	Symbol	Conditions min		typ	max	Unit
Collector cutoff current	I <sub>CBO</sub>	$V_{CB} = -400V, I_E = 0$			-100	μΑ
Emitter cutoff current	I <sub>EBO</sub>	$\mathbf{V}_{\mathbf{EB}} = -7\mathbf{V},  \mathbf{I}_{\mathbf{C}} = 0$			-100	μΑ
Collector to emitter voltage	V <sub>CEO</sub>	$I_{C} = -10 mA, I_{B} = 0$	-400			V
	h <sub>FE1</sub> *	$V_{CE} = -5V, I_C = -100mA$	30		160	
Forward current transfer ratio	h <sub>FE2</sub>	$V_{CE} = -5V, I_C = -300mA$	10			
Collector to emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = -300 {\rm mA}, I_{\rm B} = -60 {\rm mA}$			-1.0	V
Base to emitter saturation voltage	V <sub>BE(sat)</sub>	$I_{\rm C} = -300 {\rm mA}, I_{\rm B} = -60 {\rm mA}$			-1.2	v
Transition frequency	fr	$V_{CE} = -10V, I_C = -100mA, f = 1MHz$		15		MHz
Turn-on time		$I_{\rm C} = -300 {\rm mA},$			1.0	μs
Storage time	t <sub>stg</sub>	$I_{B1} = -60 \text{mA}, I_{B2} = 60 \text{mA},$			3.5	μs
Fall time	t <sub>f</sub>	$V_{CC} = -100V$			1.0	μs

\*hFE1 Rank classification

Rank	Q	Р	0
h <sub>FE1</sub>	30 to 60	50 to 100	80 to 160





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